74HC166-Q100; 74HCT166-Q100

8-bit parallel-in/serial out shift register

Rev. 1 — 25 September 2013

Product data sheet

1. General description

The 74HC166-Q100; 74HCT166-Q100 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and a serial output (Q7). When the parallel enable input (PE) is LOW, the data from D0 to D7 is loaded into the shift register on the next LOW-to-HIGH transition of the clock input (CP). When \overline{PE} is HIGH, data enters the register serially at DS with each LOW-to-HIGH transition of CP. When the clock enable input (\overline{CE}) is LOW data is shifted on the LOW-to-HIGH transitions of CP. A HIGH on \overline{CE} disables the CP input. Inputs include clamp diodes which enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Complies with JEDEC standard no. 7A
- Input levels:
 - ◆ For 74HC166-Q100: CMOS level
 - ◆ For 74HCT166-Q100: TTL level
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

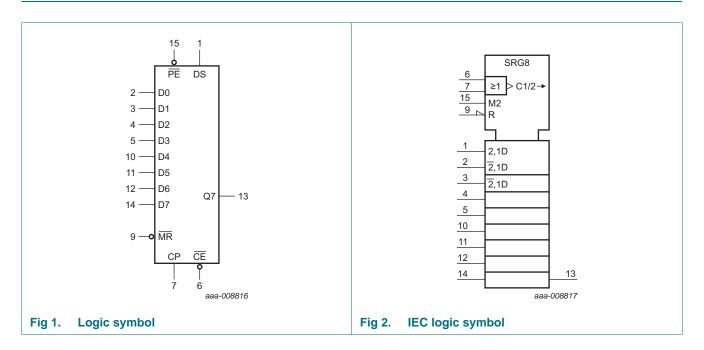
3. Ordering information

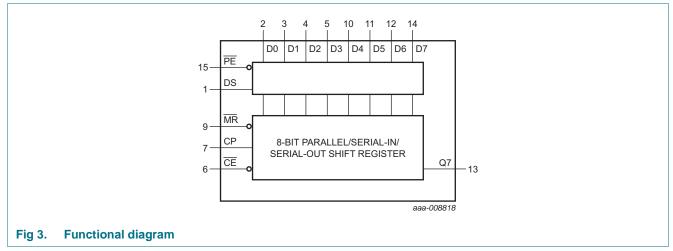
Table 1. Ordering information

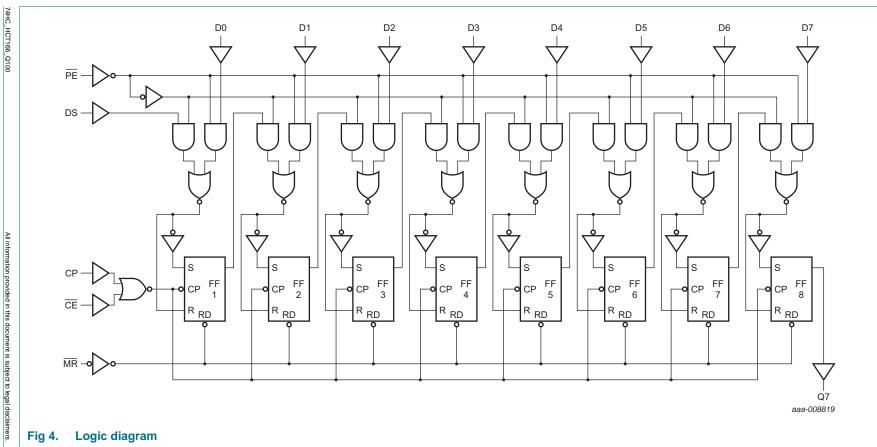
Type number	Package									
	Temperature range	Name	Description	Version						
74HC166D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body	SOT109-1						
74HCT166D-Q100			width 3.9 mm							
74HC166PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1						



4. Functional diagram

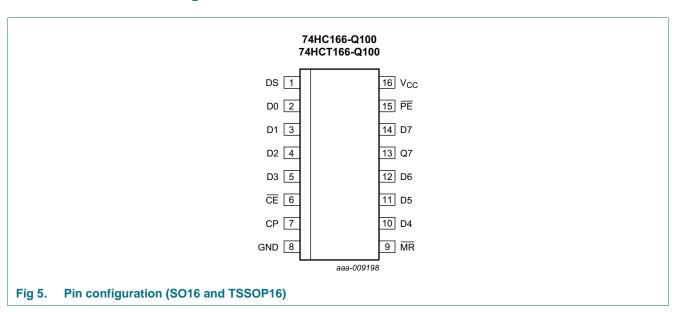






5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

	•	
Symbol	Pin	Description
DS	1	serial data input
D0 to D7	2, 3, 4, 5, 10, 11, 12, 14	parallel data inputs
CE	6	clock enable input (active LOW)
СР	7	clock input (LOW-to-HIGH edge-triggered)
GND	8	ground (0 V)
MR	9	asynchronous master reset (active LOW)
Q7	13	serial output from the last stage
PE	15	parallel enable input (active LOW)
V _{CC}	16	positive supply voltage

6. Functional description

Table 3. Function table[1]

Operating modes	Inputs			Qn regi	Qn registers			
	PE	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7
parallel load	I	I	\uparrow	Χ	I	L	L to L	L
	I	I	↑	Χ	h	Н	H to H	Н
serial shift	h	I	↑	I	X	L	q0 to q5	q6
	h	I	↑	h	X	Н	q0 to q5	q6
hold "do nothing"	Х	Н	Χ	Χ	X	q0	q1 to q6	q7

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

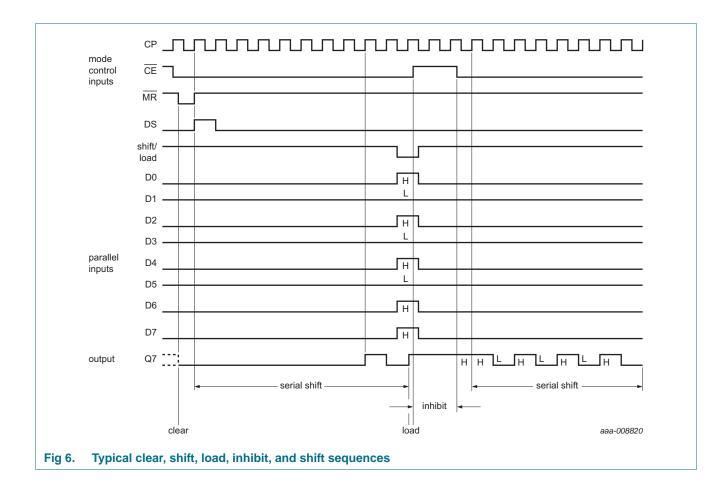
L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

 \uparrow = LOW-to-HIGH clock transition.



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
I _O	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	50	mA
I_{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$				
		SO16 package	[2	1 -	500	mW
		TSSOP16 package	[3	1 -	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] Ptot derates linearly with 8 mW/K above 70 °C.

^[3] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC16	66-Q100		74HCT	166-Q10	0	Unit
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T_{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6-Q100				•	'	1		·	
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	-	1.8	-	1.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
	$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V	
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}$; $V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
II	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	66-Q100									
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	0.8	-	8.0	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Δl _{CC}	additional supply current	per input pin; $V_{I} = V_{CC} - 2.1 \text{ V};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μΑ
		CP and CE inputs	-	80	288	-	360	-	392	μΑ
		MR input	-	40	144	-	180	-	196	μΑ
		PE input	-	60	216	-	270	-	294	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); $t_r = t_f = 6$ ns: $C_L = 50$ pF unless otherwise specified; for test circuit, see Figure 10

Symbol	Parameter	Conditions		25 °C	;	-40 °C 1	to +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6-Q100		'	·	'	'	'			
t _{pd}	propagation	CP to Q7; see Figure 7	<u>1]</u>							
	delay	V _{CC} = 2.0 V	-	50	150	-	190	-	225	ns
		$V_{CC} = 4.5 \text{ V}$	-	18	30	-	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$	-	14	26	-	33	-	38	ns
		MR to Q7; see Figure 8								
		$V_{CC} = 2.0 \text{ V}$	-	47	160	-	200	-	240	ns
		$V_{CC} = 4.5 \text{ V}$	-	17	32	-	40	-	48	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	14	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$	-	14	27	-	34	-	41	ns
t _t	transition	output; see Figure 7	2]							
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$	-	6	13	-	16	-	19	ns
t _W pulse	pulse width	CP input HIGH or LOW; see Figure 7								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$	14	5	-	17	-	20	-	ns
		MR input LOW; see Figure 8								
		V _{CC} = 2.0 V	100	25	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	9	-	25	-	30	-	ns
		$V_{CC} = 6.0 \text{ V}$	17	7	-	21	-	26	-	ns
t _{rec}	recovery time	MR to CP; see Figure 8								
		V _{CC} = 2.0 V	0	-19	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-7	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-6	-	0	-	0	-	ns
t _{su}	set-up time	Dn, CE to CP; see Figure 9								
		$V_{CC} = 2.0 \text{ V}$	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
		PE to CP; see Figure 9								
		V _{CC} = 2.0 V	100	33	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	12	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	10	-	21	-	26	-	ns

74HC_HCT166_Q100

 Table 7.
 Dynamic characteristics ...continued

GND (ground = 0 V); $t_f = t_f = 6$ ns: $C_L = 50$ pF unless otherwise specified; for test circuit, see Figure 10

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
t _h	hold time	Dn, CE to CP; see Figure 9									
		V _{CC} = 2.0 V		2	-8	-	2	-	2	-	ns
		V _{CC} = 4.5 V		2	-3	-	2	-	2	-	ns
		V _{CC} = 6.0 V		2	-2	-	2	-	2	-	ns
		PE to CP; see Figure 9									
		V _{CC} = 2.0 V		0	-28	-	0	-	0	-	ns
		V _{CC} = 4.5 V		0	-10	-	0	-	0	-	ns
		$V_{CC} = 6.0 \text{ V}$		0	-8	-	0	-	0	-	ns
f _{max}	maximum	CP input; see Figure 7									
	frequency	V _{CC} = 2.0 V		6	19	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V		30	57	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	63	-	-	-	-	-	MHz
		$V_{CC} = 6.0 \text{ V}$		35	68	-	28	-	24	-	MHz
C_PD	power dissipation capacitance	per package; $V_I = GND$ to V_{CC}	[3]	-	41	-	-	-	-	-	pF
74HCT10	66-Q100										
propagation	CP to Q7; see Figure 7	[1]									
•	delay	V _{CC} = 4.5 V		-	23	40	-	50	-	60	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		MR to Q7; see Figure 8									
		$V_{CC} = 4.5 \text{ V}$		-	22	40	-	50	-	60	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	19	-	-	-	-	-	ns
t _t	transition	output; see Figure 7	[2]								
	time	V _{CC} = 4.5 V		-	7	15	-	19	-	22	ns
t _W	pulse width	CP input HIGH or LOW; see Figure 7									
		V _{CC} = 4.5 V		20	9	-	25	-	30	-	ns
		MR input LOW; see Figure 8									
		V _{CC} = 4.5 V		25	11	-	31	-	38	-	ns
t _{rec}	recovery time	MR to CP; see Figure 8									
		V _{CC} = 4.5 V		0	-7	-	0	-	0	-	ns
t _{su}	set-up time	Dn, CE to CP; see Figure 9									
		V _{CC} = 4.5 V		16	8	-	20	-	24	-	ns
		PE to CP; see Figure 9									
		V _{CC} = 4.5 V		30	15	-	38	-	45	-	ns
t _h	hold time	Dn, CE to CP; see Figure 9									
		V _{CC} = 4.5 V		0	-3	-	0	-	0	-	ns
		PE to CP; see Figure 9									
		V _{CC} = 4.5 V		0	-13		0		0		ns

74HC_HCT166_Q100

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Table 7. Dynamic characteristics ...continued

GND (ground = 0 V); $t_r = t_f = 6$ ns: $C_L = 50$ pF unless otherwise specified; for test circuit, see <u>Figure 10</u>

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
f_{max}	maximum	CP input; see Figure 7									
	frequency	$V_{CC} = 4.5 \text{ V}$		25	45	-	20	-	17	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	50	-	-	-	-	-	MHz
C_{PD}	power dissipation capacitance	per package; $V_I = GND$ to V_{CC}	[3]	-	41	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

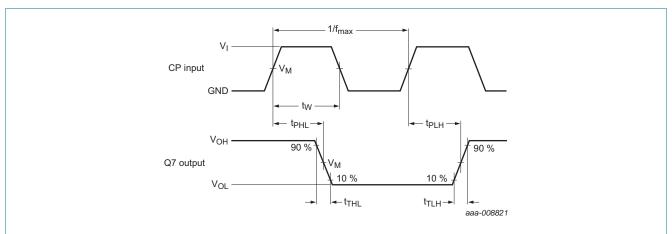
f_o = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs};$

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

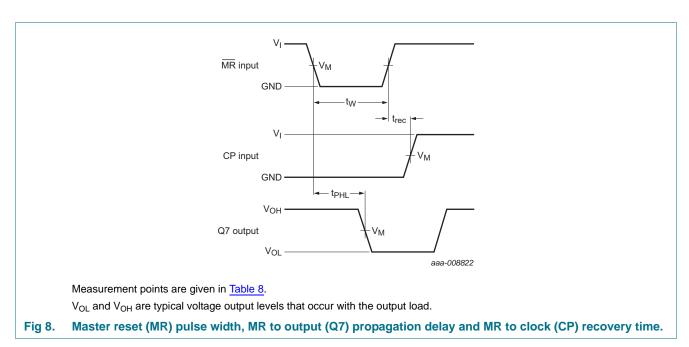
11. Waveforms



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 7. Clock (CP) to output (Q7) propagation delays, pulse width, output transition times and maximum frequency



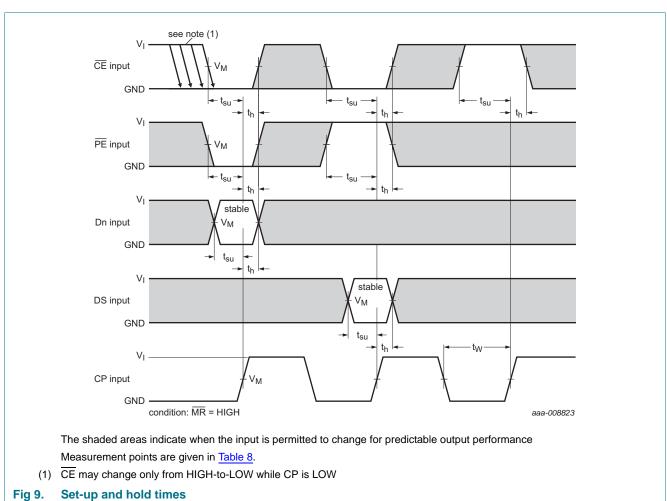
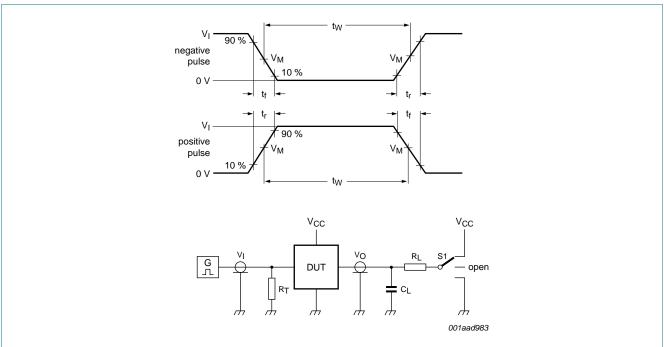


Table 8. Measurement points

Туре	Input		Output
	VI	V _M	V _M
74HC166-Q100	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT166-Q100	3 V	1.3 V	1.3 V



Test data is given in Table 10.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

S1 = Test selection switch

Fig 10. Test circuit for measuring switching times

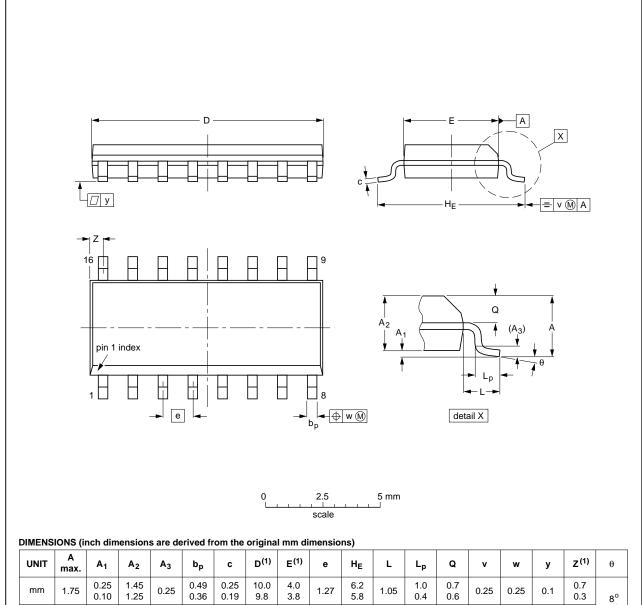
Table 9. Test data

Туре	Input		Load	S1 position	
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}
74HC166-Q100	V_{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT166-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	l	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

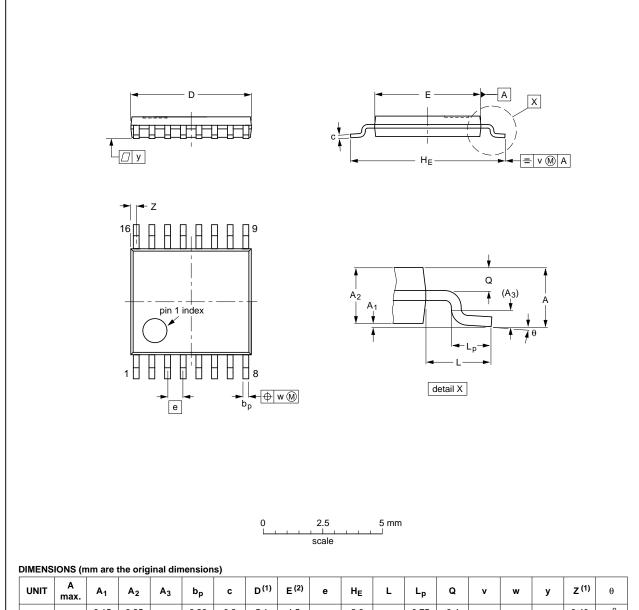
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VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 11. Package outline SOT109-1 (SO16)

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				99-12-27 03-02-18	

Fig 12. Package outline SOT403-1 (TSSOP16)

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT166_Q100 v.1	20130925	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors

8-bit parallel-in/serial out shift register

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